

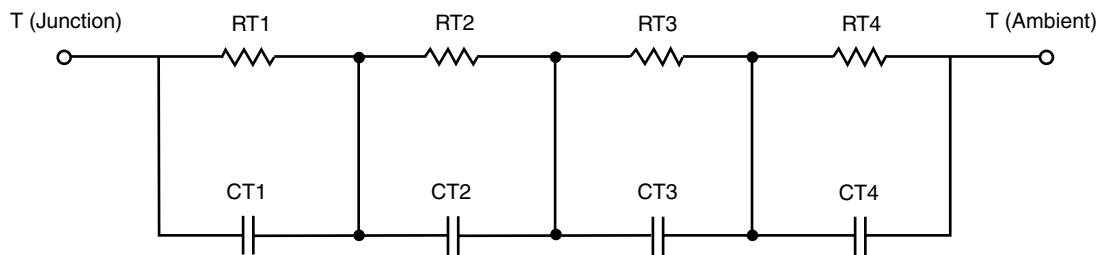
## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION

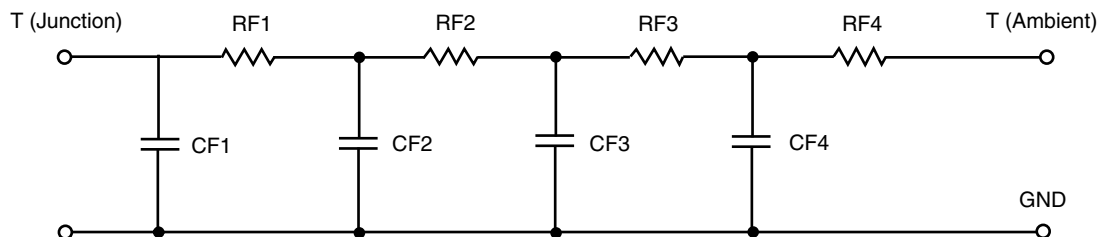


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	13.1050	1.3523	N/A
RT2	27.0718	5.6589	N/A
RT3	26.9401	5.0019	N/A
RT4	42.8831	3.9869	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	96.2070 u	1.0155 m	N/A
CT2	2.0933 m	564.8306 u	N/A
CT3	34.5359 m	55.9280 u	N/A
CT4	1.1437	357.4204 u	N/A

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	14.4086	6.6789	N/A
RF2	28.3271	4.9199	N/A
RF3	25.9635	2.7079	N/A
RF4	41.3008	1.6933	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	108.8115 u	37.0761 u	N/A
CF2	1.8188 m	118.4691 u	N/A
CF3	33.0691 m	211.8647 u	N/A
CF4	1.1423	980.4259 u	N/A

**Note**

N/A indicates not applicable

